LOW-NOISE DUAL OPERATIONAL AMPLIFIER

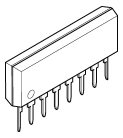
■ GENERAL DESCRIPTION

The NJM5532 is a high performance dual low noise operational amplifier. Compared to the standard dual operational amplifiers, such as the NJM1458, it shows better noise performance, improved output drive capability, and considerably higher small-signal and power bandwidths. it is compensated internally for voltage follower circuit. This makes the device especially suitable for application in high quality and professional audio equipment, instrumentation, control circuits, and telephone channel amplifiers.

If very low noise characteristic is of prime importance, it is recommended D-Rank type products(NJM5532DD/LD/MD). These have specified maximum limits for equivalent input noise voltage.

■ PACKAGE OUTLINE

NJM5532D
(DIP8)



NJM5532L
(SIP8)

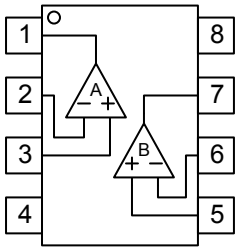
NJM5532M
(DMP8)

■ FEATURES

● Operating Voltage	±3V~±22V
● Small Signal Bandwidth	10MHz typ.
● Output Drive Capability	600Ω,10Vrms typ.
● Input Noise Voltage	5nV/√Hz typ.
● Power Bandwidth	140kHz typ.
● Slew Rate	8V/μs typ.
● Bipolar Technology	
● Package Outline	DIP8,DMP8,SIP8

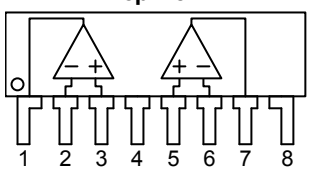
■ PIN CONFIGURATION

Top View



DIP8, DMP8 Package

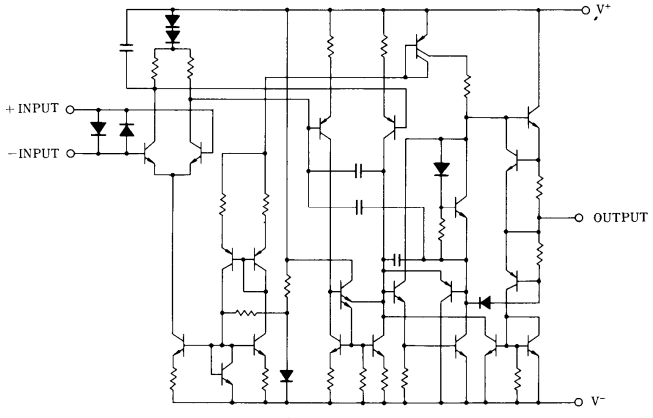
Top View



SIP8 Package

PIN FUNCTION
1.A OUTPUT
2.A -INPUT
3.A +INPUT
4.V^-
5.B +INPUT
6.B -INPUT
7.B OUTPUT
8.V^+

■ EQUIVALENT CIRCUIT (1/2 Shown)



■ ABSOLUTE MAXIMUM RATINGS (Ta=25˚C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V^+/V^-	±22	V
Common Mode Input Voltage Range	V_{ICM}	V^+/V^-	V
Differential Input Voltage Range	V_{ID}	±0.5	V
Power Dissipation	P_D	DIP8 : 500 DMP8 : 600(Note1) SIP8 : 800	mW
Operating Temperature Range	Topr	-20~+75	°C
Storage Temperature Range	Tstg	-40~+125	°C

(Note1) On the cermic PCB (10x20x0.635mm)

■ RECOMMENDED OPERATING VOLTAGE (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V^+/V^-	±3~±22	V

■ ELECTRICAL CHARACTERISTICS (V^+/V^-=±15V,Ta=25˚C, unless otherwise noted.)

● DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	R_S≤10kΩ	-	0.5	4	mV
Input Offset Current	I_{IO}		-	10	150	nA
Input Bias Current	I_B		-	200	800	nA
Supply Current	I_{CC}	R_L=∞	-	9	16	mA
Common Mode Input Voltage Range	V_{ICM}		± 12	± 13	-	V
Common Mode Rejection Ratio	CMR	R_S≤10kΩ	70	100	-	dB
Supply Voltage Rejection Ratio	SVR	R_S≤10kΩ	80	100	-	dB
Voltage Gain1	A_{V1}	R_L≥2kΩ, V_O=±10V	88	100	-	dB
Voltage Gain2	A_{V2}	R_L≥600Ω, V_O=±10V	83.5	94	-	dB
Maximum Output Voltage1	V_{OM1}	R_L≥600Ω	± 12	± 13	-	V
Maximum Output Voltage2	V_{OM2}	R_L≥600Ω, V^+/V^-=±18V	± 15	± 16	-	V
Input Resistance	R_{IN}		30	300	-	kΩ
Short Circuit Output Current	I_{OS}		-	38	-	mA

● AC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Resistance	R_O	A_V=30dB,f=10kHz, R_L=600Ω	-	0.3	-	Ω
Overshoot		A_V=1, V_{IN}=100mV_{PP}, R_L=100pF, R_L=600Ω	-	10	-	%
Voltage Gain	A_V	f=10kHz	-	67	-	dB
Slew Rate	SR		-	8	-	V/μs
Gain Bandwidth Product	GB	C_L=100pF, R_L=600Ω	-	10	-	MHz
Power Bandwidth	W_{PG}	V_O=±10V	-	140	-	kHz
	W_{PG}	V_O=±14V, R_L=600Ω, V^+/V^-=±18V	-	100	-	kHz
Equivalent Input Noise Voltage	e_n	f_O=30Hz	-	8	-	nV/√Hz
	e_n	f_O=1kHz	-	5	-	nV/√Hz
Equivalent Input Noise Current	i_n	f_O=30Hz	-	2.7	-	pA/√Hz
	i_n	f_O=1kHz	-	0.7	-	pA/√Hz
Channel Separation	CS	f=1kHz, R_S=5kΩ	-	110	-	dB

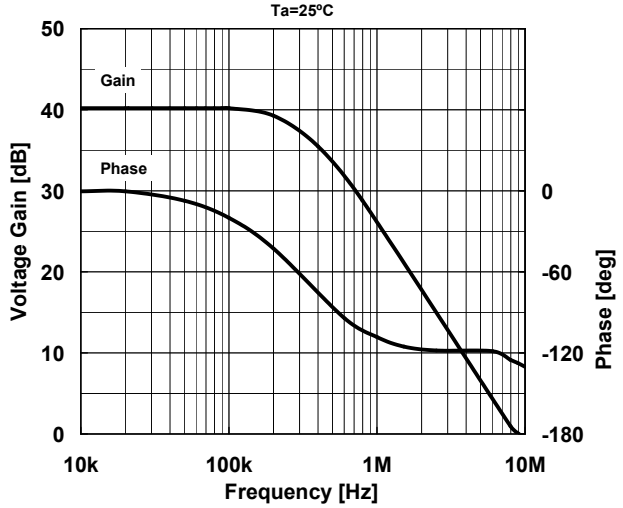
■ ELECTRICAL CHARACTERISTICS (D-ranktype(Note2), V^+/V^-=±15V, Ta=25˚C, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Equivalent Input Noise Voltage	V_{NI}	RIAA, R_S=2.2kΩ	-	-	1.4	μVrms

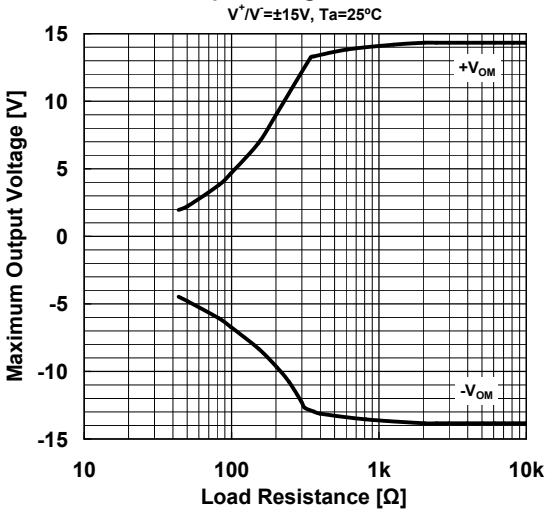
(Note2)D-rank type is a Equivalent Input Noise Voltage selected product.

■ TYPICAL CHARACTERISTICS

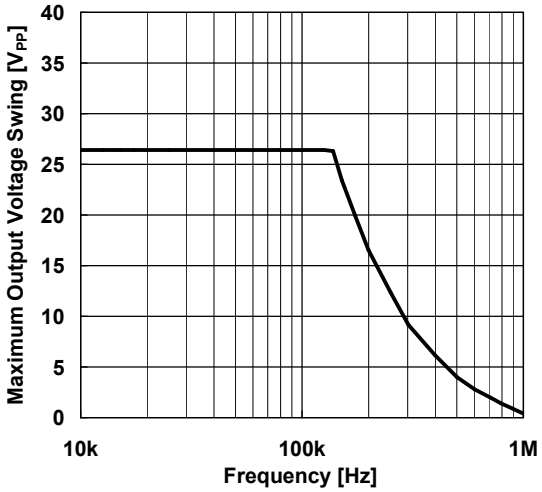
Gain/Phase vs. Frequency
Ta=25ºC



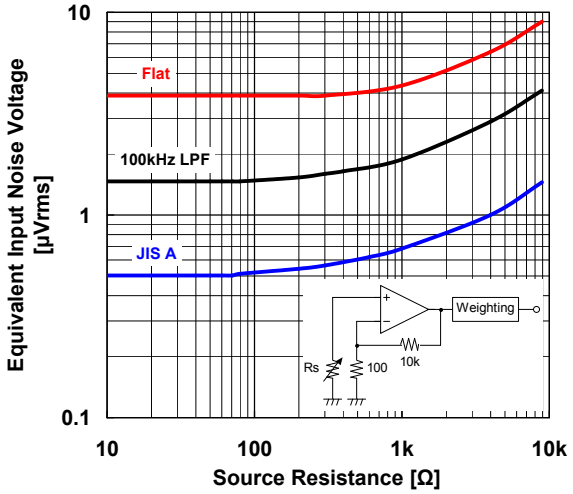
Maximum Output Voltage vs. Load Resistance
V⁺/V⁻=±15V, Ta=25ºC



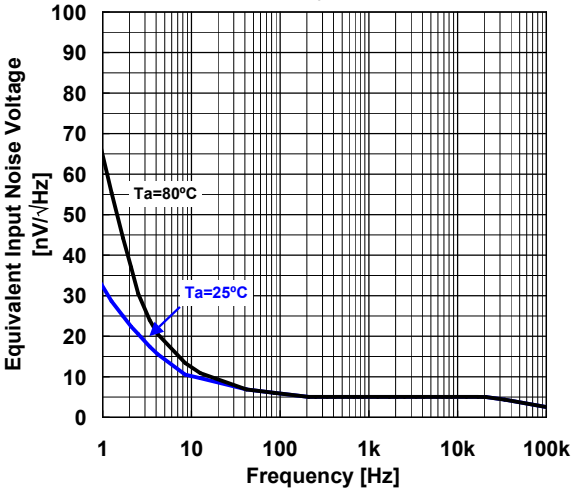
Maximum Output Voltage Swing vs. Frequency
V⁺/V⁻=±15V, Ta=25ºC



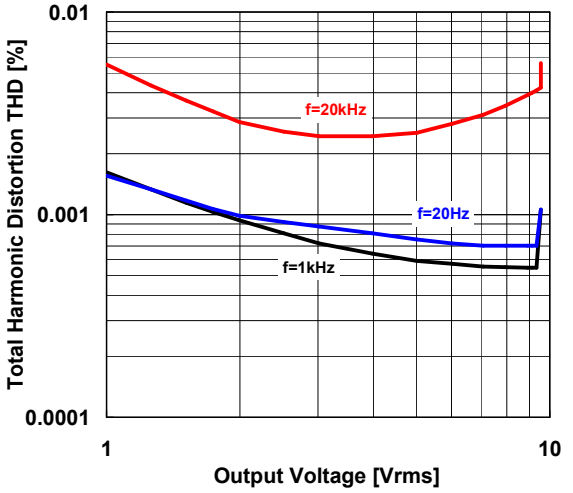
Voltage Noise vs. Source Resistance
V⁺/V⁻=±15V, Ta=25ºC



Voltage Noise vs. Frequency
V⁺/V⁻=±15V, RS=50Ω, AV=60dB

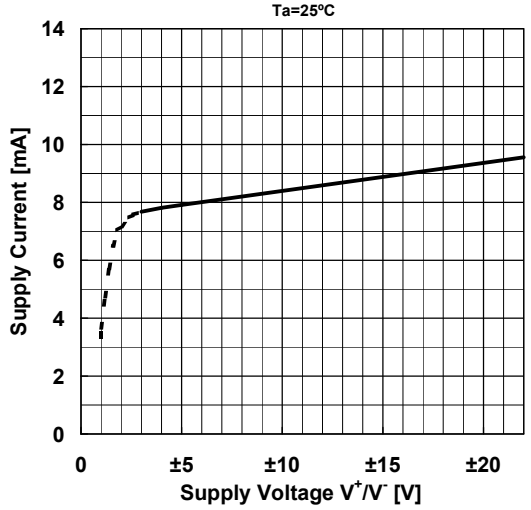


THD vs. Output Voltage
V⁺/V⁻=±15V, RL=10kΩ, GV=20dB, Ta=25ºC

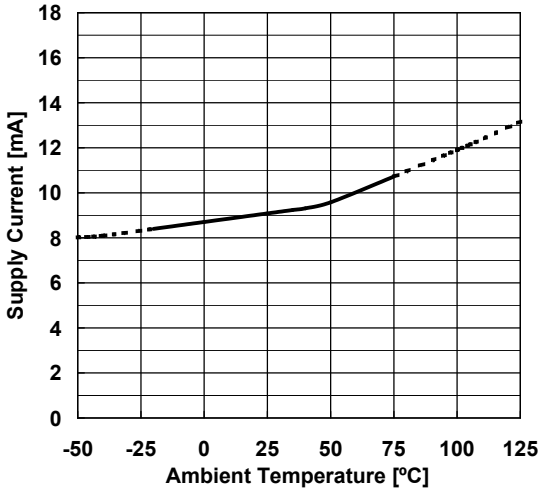


■ TYPICAL CHARACTERISTICS

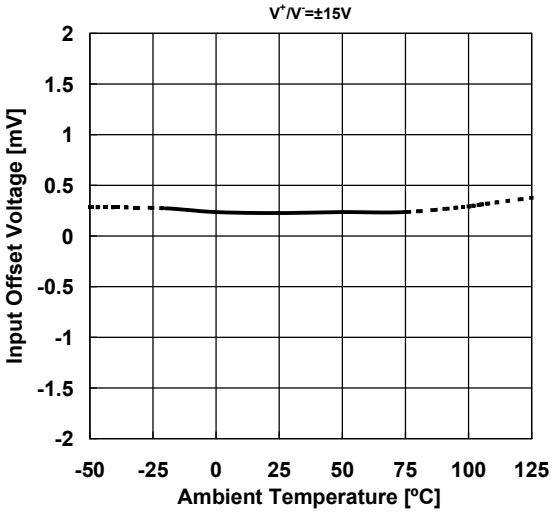
Supply Current vs. Supply Voltage
Ta=25ºC



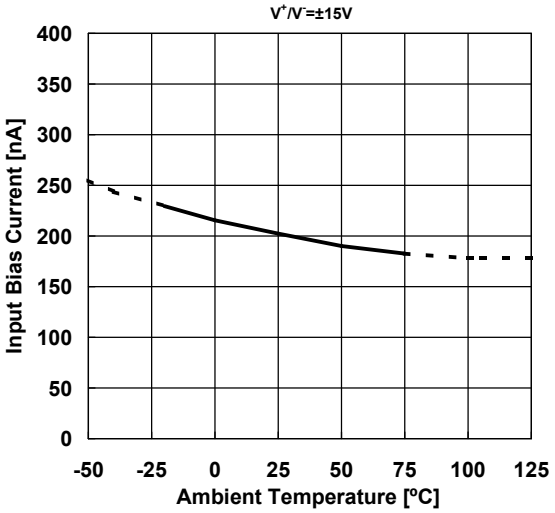
Supply Current vs. Temperature
V+/V-=±15V



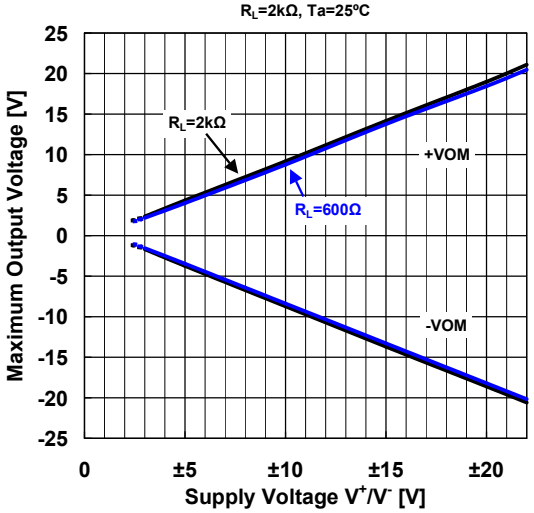
Input Offset Voltage vs. Temperature
V+/V-=±15V



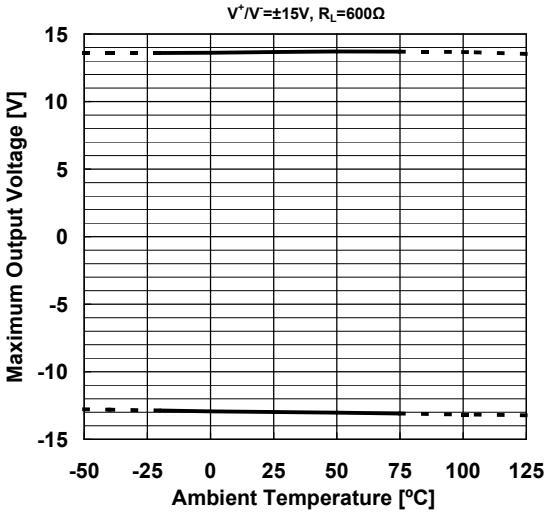
Input Bias Current vs. Temperature
V+/V-=±15V



Maximum Output Voltage vs. Supply Voltage
RL=2kΩ, Ta=25ºC

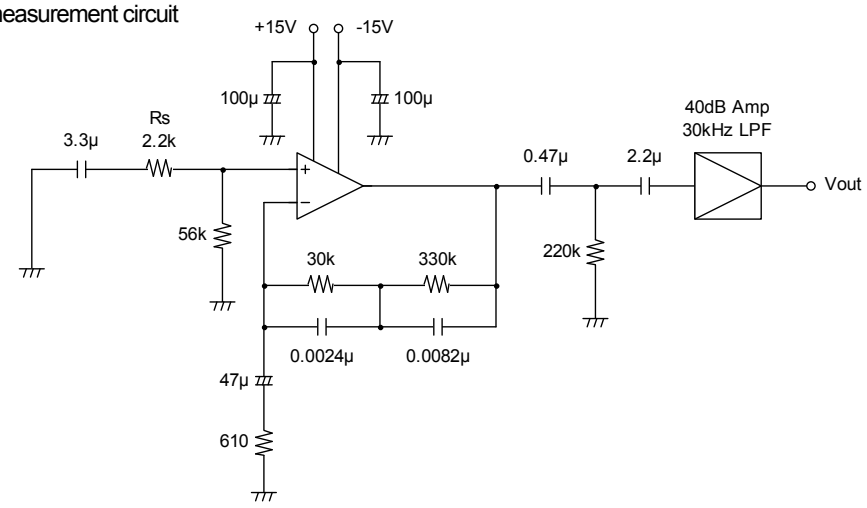


Maximum Output Voltage vs. Temperature
V+/V-=±15V, RL=600Ω



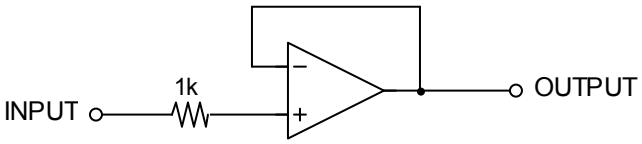
■ TEST CIRCUIT

Noise Voltage (RIAA) measurement circuit



■ NOTICE

When used in voltage follower circuit, put a current limit resistor into non-inverting input terminal in order to avoid inside input diode destruction when the power supply is turned on. (ref.Fig.1)



(Fig.1)

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